

1.0A High Side Power Switch With Flag

❖ GENERAL DESCRIPTION

AX8711/AX8721 is a low voltage, single NMOSFET high-side power switch, optimized for self-powered and bus-powered Universal serial bus (USB) application. AX8711/AX8721 equipped with a charge pump circuitry to drive the internal NMOSFET switch, the switch's low Rds(on) 80mΩ. meets USB voltage droop requirement and a flag output is available to indicate fault conditions to the local USB controller.

Additional features include soft-start to limit the inrush current during plug-in, thermal shutdown to prevent catastrophic switch failure from high-current loads, under voltage lockout (UVLO) to ensure that the device remains off unless there is a valid input voltage present. The maximum current is limited to typically 1.5A in dual ports in accordance with the USB power requirement. The low quiescent current as 35uA makes this device ideal for portable battery operated equipment.

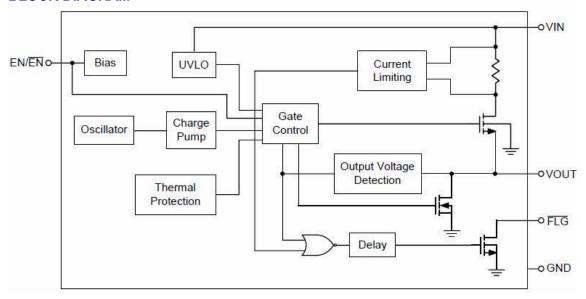
AX8711/AX8721 is available in SOT-23-5L, SOP-8L and MSOP-8L packages requiring minimum board space and few peripheral components.

❖ FEATURES

- Wide Input Voltage Range: 2.5V to 5.5V
- Compliant to USB Specifications
- AX8711/AX8721 Enable Active Low/High
- Typical Rdson $70m\Omega$ (SOT-23-5L) $80m\Omega$ (SOP-8L/MSOP-8L)
- Typical 2.1V under voltage lockout
- Output can be forced higher than input (Off-state)
- Low supply current Less than 1uA at the off state 35uA at switch on state
- Guaranteed 1.0A continuous load current
- Open Drain Fault Flag Output
- Hot Plug-In Application(Soft start)
- Current Limiting Protection
- Thermal Shutdown Protection
- Reverse Current Flow Blocking (no body diode)
- UL Approved-E353665
- TuV EN60950-1 Certification
- CB IEC60950-1 Certification

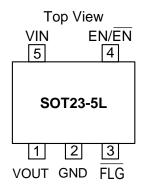


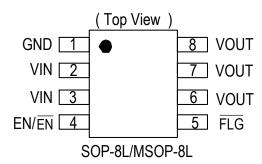
*** BLOCK DIAGRAM**



❖ PIN ASSIGNMENT

The pin assignment is given by:

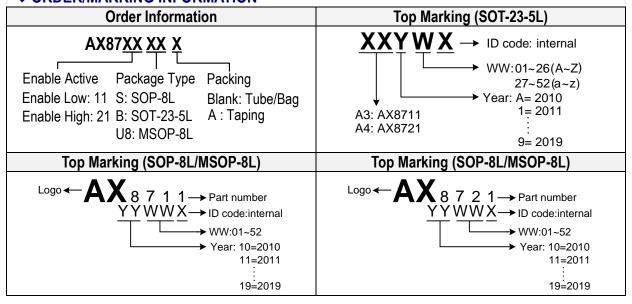




Name	Pin No. SOT23-5L	Pin No. SOP-8 /MSOP-8	Description
VOUT	1	6,7,8	Output Voltage.
GND	2	1	Ground.
FLG	3	5	Fault FLAG Output.
EN/EN	4	4	Chip Enable (Active High/Low).
VIN	5	2,3	Power Input Voltage.



❖ ORDER/MARKING INFORMATION



❖ ABSOLUTE MAXIMUM RATINGS (at T_A=25°C)

Characteristics	,	Symbol Rating			
Supply Input Voltage		V_{IN}	6.5	V	
EN Input Voltages			-0.3 to 6.5	V	
FLAG Voltage			6.5	V	
Package Power Dissipation	P _D	PD= $(T_J-T_A)/\theta_{JA}$	mW		
Operating Temperature Range			°C		
Junction Temperature		TJ	-40~125	°C	
Storage Temperature Range		Ts	-65 to +150	°C	
ESD Rating (Note)	HBM (Human Body Mode)		2	kV	
,	MM (Machine Mode)		200	V	
	SOP-8L		160		
Thermal Resistance from Junction to ambient	SOT-23-5L	θ_{JA}	250	°C/W	
	MSOP-8L 1		160		
	SOP-8L		60	°C/W	
Thermal Resistance from Junction to case	SOT-23-5L	θјс	130		
	MSOP-8L		55		

Note: Absolute Maximum Ratings are the values beyond which the life of the device may be impaired.



*** ELECTRICAL CHARACTERISTICS**

(V_{IN}=5V, C_{IN}=1uF, C_{OUT}=10uF, T_A = 25°C, unless otherwise specified)

Characteristics		Symbol	Cond	litions	Min	Тур	Max	Units
Input Voltage Range	tage Range V _{IN}		2.5	-	5.5	V		
Under Voltage Locko	Under Voltage Lockout		V _{IN} Increase		1.7	2.1	2.4	V
Under Voltage Hyste	resis		V _{IN} Decrease		-	100	-	mV
Input Leakage Curre	nt	I _{LEAK}	Disabled, OUT grou	nded		0.1	1	μΑ
Output Leakage Curr	ent		Disabled, R _{LOAD} =0Ω		-	0.5	10	μΑ
Reverse Leakage Cu	ırrent	I _{REV}	Disabled, V _{IN} = 0V, V _{OUT} = 5V, I _{REV} at V _{IN}			0.1	1	μΑ
			V _{IN} =5.0V, I _{OUT} =1A, T _A = 25°C		-	70	100	
Cwitch On Desigtor			SOT-23-5L	-40°C ≤ T _A ≤ 85°C			140	O
Switch On Resistor		RDSON	V _{IN} =5.0V, I _{OUT} =1A,	T _A = 25°C	-	80	110	mΩ
			SOP-8L/MSOP-8L	-40°C ≤ T _A ≤ 85°C	-	ı	140	
Cummby Cummant		ΙQ	Switch On, V _{OUT} = C	PEN	-	35	45	
Supply Current		I _{SHDN}	Switch Off, V _{OUT} = OPEN		-	0.1	1	μΑ
EN Threshold	AX8721	V _{IL}	Low Voltage		-	-	0.7	V
LIN THIESHOLD	ANOTZI	V _{IH} High Voltage		2.0	-	-	V	
EN Threshold	AX8711	V_{IH}	High Voltage		-	-	0.7	V
EN THIESHOID	ΑΛ0111	V_{IL}	Low Voltage		2.0	-	-	V
EN/EN Input Currer	nt	I _{SINK}	VEN/EN From 0V to 5V		-	0.01		μΑ
Current Limit	Current Limit		V _{IN} = 5V, V _{OUT} = 4.5V	-40°C ≤ T _A ≤85°C	1.1	1.5	1.9	Α
Output Turn-on Risa	Time	T _R	V_{IN} =3.3V, C_{L} =1 μ F, R_{load} =3 Ω , V_{OUT} Rise From 10% to 90%		-	1.5	-	ms
Output Turn-on Rise Time		'R	V_{IN} =5.0V, C_{L} =1 μ F, R_{load} =5 Ω , V_{OUT} Rise From 10% to 90%		-	1.5	-	ms
Output Turn-on Delay Time		T _{D(ON)}	C_L =1μF, R_{load} =10Ω, EN 10% (EN 90%) to V_{OUT} 10%		-	20	-	us
Output Turn-off Fall Time		T _F	C_L =1 μ F, R_{load} =10 Ω , V_{OUT} Fall From 90% to 10%		-	20	-	us
Output Turn-off Delay	y Time	T _{D(OFF)}	C_L =1μF, $R_{\underline{load}}$ =10Ω, EN 90% (EN 10%) to V_{OUT} 90%		-	10	-	us



❖ ELECTRICAL CHARACTERISTICS (CONTINUOUS)

(V_{IN}=5V, C_{IN}=1uF, C_{OUT}=10uF, T_A = 25°C, unless otherwise specified)

Characteristics	Symbol	Conditions	Min	Тур	Max	Units
FLG Output Resistor	R_{FLG}	I _{SINK} =1mA	-	20	40	Ω
FLG Off Current		$V_{\overline{\scriptscriptstyle FLG}}$ = 5V	ı	0.01	1	μΑ
FLG DELAY TIME	I I Blank	From Fault Condition to \overline{FLG} assertion	5	15	20	ms
Output Shutdown Discharge Resistance		Disabled	ı	100	150	Ω
Thermal Shutdown Threshold	T _{SD}	Enabled	1	150	-	ů
Thermal Shutdown Hysteresis	T _{HYS}	V _{OUT} = 0V		20	-	°C

Note 1: Thermal Resistance is specified with approximately 1 square of 1 oz copper.

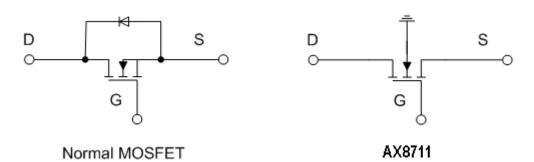
Note 2: 100% production test at +25°C. Specifications over the temperature range are guaranteed by design and characterization. The device is not guaranteed to function outside its operating conditions.

APPLICATION INFORMATION

The AX8711/8721 is a single N-MOSFET high-side power switch with enable input, optimized for self-powered and bus-powered Universal Serial Bus (USB) applications. The AX8711/AX8721 series are equipped with a charge pump circuitry to drive the internal N-MOSFET switch: The switch's low Rds(on).80mΩ meets USB voltage drop requirements and a flag output is available to indicate fault conditions to the local USB controller.

Input and Output

V_{IN} (Input) is the power source connection to the internal circuitry and the drain of the N-MOSFET. V_{OUT} (Output) is the source of the N-MOSFET. In a typical application, current flows through the switch from V_{IN} to V_{OUT} toward the load. If V_{OUT} is greater than V_{IN}, current will flow from V_{OUT} to V_{IN} since the MOSFET is bidirectional when on. Unlike a normal MOSFET, there is no a parasitic body diode between drain and source of the MOSFET, the AX8711/8721 prevents reverse current flow if V_{OUT} being externally forced to a higher voltage than V_{IN} when the output disabled $(V_{EN} < 0.8V \text{ or } V_{EN} > 2V).$





Enable

The switch will be disabled when the EN pin is low or $\overline{\text{EN}}$ is high. During this condition, the internal circuitry and MOSFET are all turned off and the supply current reduces to 0.1uA typically. Floating the $\overline{\text{EN/EN}}$ may cause unpredictable operation. EN should not be allowed to be negative to GND. The $\overline{\text{EN/EN}}$ pin may be directly tied to VIN (GND) to keep the part on.

UVLO

Under-Voltage Lockout (UVLO) prevents the power MOSFET from turning on until the input voltage is up to approximately 2.1V. If the input voltage drops blow about 2.0V, UVLO turns off the power MOSFET switch and \overline{FLG} will be asserted accordingly. Under voltage protection is function when the part is enabled.

Soft Start for Hot Plug Application

In order to eliminate the upstream voltage droop caused by the large inrush current during the hot plug events, the soft start feature effectively isolates the power source from extremely large load capacitor, satisfying the USB voltage droop requirement.

Fault Flag

The AX8711/AX8721 series provides a \overline{FLG} signal pin which is an N-Channel open drain MOSFET output. This open drain output goes low when $V_{OUT} < V_{IN} - 1V$, current limit or the die temperature exceeds 150°C approximately. The \overline{FLG} output is typically about 200mV when sinking a 10mA load. A 100K pull up resistor is required at the \overline{FLG} pin. \overline{FLG} Pin will be asserted at the over-current condition after the flag response delay time TD. This ensures that \overline{FLG} is asserted only at the valid over-current conditions and error reporting is eliminated.

Current Limiting and Short-Circuit Protection

The current limit circuitry prevents damage to the MOSFET switch and the hub downstream port but can deliver load current up to the current limit threshold of typically 2.5A through the switch of AX8711/AX8721. When a heavy load or short circuit is applied to an enabled switch, a large transient current may flow until the current limit circuitry responds. Once this current limit threshold is exceeded the device enters constant current mode until the thermal shutdown occurs or the fault is removed.

Thermal Shutdown

Thermal shutdown is employed to protect the device from damage if the die temperature exceeds approximately 150° C. If enabled, the switch automatically restarts when the die temperature falls 20° C. The output and \overline{FLG} signal will continue to cycle on and off until the device is disabled or the fault is removed.



Input capacitor

A 1uF low ESR ceramic capacitor from $V_{\rm IN}$ to GND, located at the device is strongly recommended to prevent the input voltage drooping during hot-plug events. However, higher capacitor values will further reduce the voltage droop at the input. Furthermore, without the bypass capacitor, an output short may cause sufficient ringing on the input (from source lead inductance) to destroy the internal control circuitry. The input transient must not exceed 6.5V of the absolute maximum supply voltage even for a short duration.

Output capacitor

A low ESR 150 μ aluminum electrolytic or tantalum between V_{OUT} and GND is strongly recommended to meet the 330 μ V maximum droop requirement in the hub VBUS (Per USB 2.0, output ports must have a minimum 120 μ F of low ESR bulk capacitor per hub). Standard bypass methods should be used to minimize inductance and resistance between the bypass capacitor and the downstream connector to reduce EMI and decouple voltage droop caused when downstream cables are hot insertion transients. Ferrite beads in series with VBUS, the ground line and the 0.1 μ F bypass capacitors at the power connector pins are recommended for EMI and ESD protection. The bypass capacitor itself should have a low dissipation factor to allow decoupling at higher frequencies.

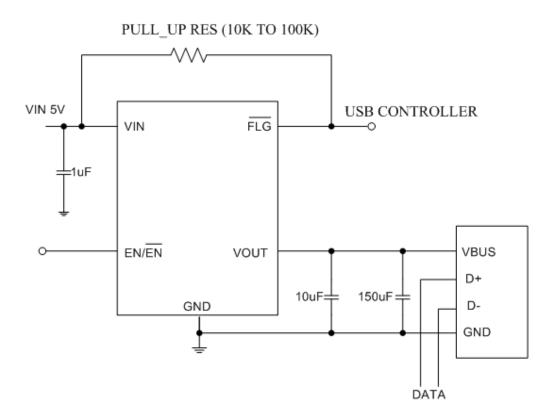
PCB Layout Guide

For best performance of the AX8711/AX8721 series, the following guidelines must be strictly followed:

- 1. Input and output capacitors should be placed close to the IC and connected to ground plane to reduce noise coupling.
- 2. The GND should be connected to a strong ground plane for heat sink.
- 3. Keep the main current traces as possible as short and wide.



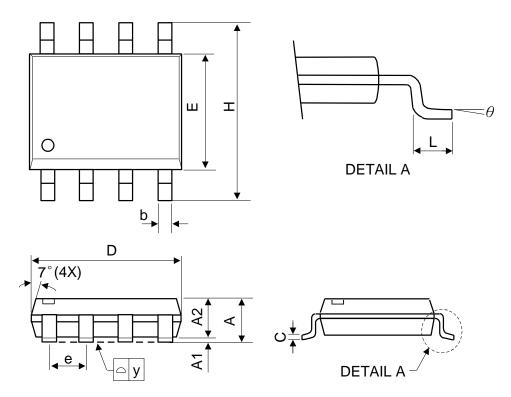
*** APPLICATION CIRCUIT**





*** PACKAGE OUTLINES**

(1) SOP-8L



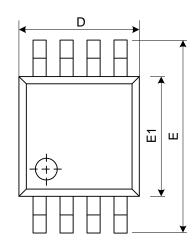
Symbol	Dimensions in Millimeters			Dimensions in Inches		
Symbol	Min.	Nom.	Max.	Min.	Nom.	Max.
Α	-	-	1.75	-	-	0.069
A1	0.1	-	0.25	0.04	-	0.1
A2	1.25	-	-	0.049	-	-
С	0.1	0.2	0.25	0.0075	0.008	0.01
D	4.7	4.9	5.1	0.185	0.193	0.2
E	3.7	3.9	4.1	0.146	0.154	0.161
Н	5.8	6	6.2	0.228	0.236	0.244
L	0.4	-	1.27	0.015	-	0.05
b	0.31	0.41	0.51	0.012	0.016	0.02
е	1.27 BSC				0.050 BSC	
у	-	-	0.1	-	-	0.004
θ	00	-	80	00	-	8 0

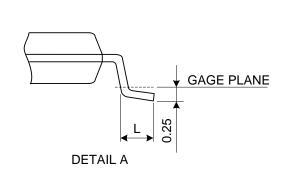
Mold flash shall not exceed 0.25mm per side

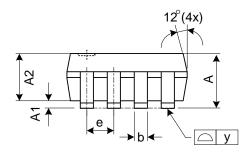
JEDEC outline: MS-012 AA

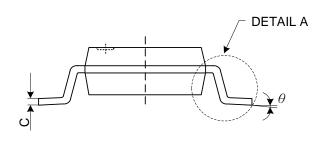


(2) MSOP-8L







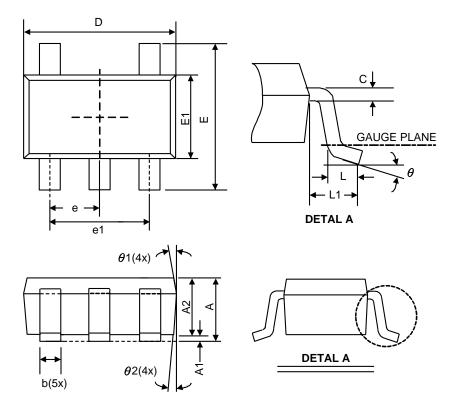


Symbol	Dim	Dimensions in Millimeters			Dimensions in Inches			
Symbol	Min.	Nom.	Max.	Min.	Nom.	Max.		
Α	-	-	1.10	-	-	0.043		
A1	0.00	0.08	0.15	0.000	0.003	0.006		
A2	0.75	0.85	0.95	0.030	0.033	0.037		
b	0.22	0.30	0.38	0.009	0.012	0.015		
С	0.08	0.15	0.23	0.003	0.006	0.009		
D	2.90	3.00	3.10	0.114	0.118	0.122		
E	4.80	4.90	5.00	0.189	0.193	0.197		
E1	2.90	3.00	3.10	0.114	0.118	0.122		
е		0.65 BSC		0.026 BSC				
L	0.40	0.60	0.80	0.016	0.024	0.031		
у	-	-	0.1	-	-	0.004		
θ	0°	4°	8°	0°	4°	8°		

JEDEC outline: MO-187 AA



(3) SOT-23-5L



Cumbal	Dimensions in Millimeters			Dimensions in Inches			
Symbol	Min.	Nom.	Max.	Min.	Nom.	Max.	
Α	-	-	1.45	-	-	0.057	
A1	0.00	0.08	0.15	0	0.003	0.006	
A2	0.90	1.10	1.30	0.035	0.043	0.051	
b	0.30	0.40	0.50	0.012	0.016	0.020	
С	0.08	0.15	0.22	0.003	0.006	0.009	
D	2.70	2.90	3.10	0.106	0.114	0.122	
E1	1.40	1.60	1.80	0.055	0.063	0.071	
E	2.60	2.80	3.00	0.102	0.110	0.118	
L	0.30	0.45	0.60	0.012	0.018	0.024	
L1	0.50	0.60	0.70	0.020	0.024	0.028	
e1		1.9 BSC	0.075 BSC				
е		0.95 BSC		0.037 BSC			
θ	0°	40	80	00	4 º	8°	
θ 1	5°	10°	15∘	5∘	10°	15°	
θ 2	5°	10∘	15∘	5∘	10°	15°	

JEDEC outline: MO-178 AA